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NTE4510B & NTE4510BT Integrated Circuit CMOS, Presettable Up/Down BCD Counter

Description:

The NTE4510B (16-Lead DIP) and NTE4510BT (SOIC-16) are up/down counters constructed with MOS P-channel and N-channel enhancement mode devices in a single monolithic structure. The counter consists of type D flip-flop stages with a gating structure to provide type T flip-flop capability. The counter can be cleared by applying a high level on the Reset line. These complementary MOS counters find primary use in up/down and difference counting and frequency synthesizer applications where low power and/or high noise immunity is desired. They are also useful in A/D and D/A conversion for magnitude and sign generation.

Features:

- Noise Immunity = 45% of V_{DD} (Typ)
- Diode Protection on All Inputs
- Supply Voltage Range = 3Vdc to 10Vdc
- Low Input Capacitance = 5pF (Typ)
- Internally Synchronous for High Speed
- Logic Edge-Clocked Design – Count Occurs on Positive Going Edge of Clock
- 5Mhz Counting Rate
- Asynchronous Preset Enable Operation
- Capable of Driving Two Low-Power TTL Loads, One Low-Power Schottky TTL Load or Two HTL Loads Over the Rated Temperature Range

Absolute Maximum Ratings: (Voltages Referenced to V_{SS} , Note 1)

DC Supply Voltage, V_{DD}	-0.5 to +18.0V
Input Voltage (All Inputs), V_{in}	-0.5 to $V_{DD} + 0.5V$
DC Current Drain (Per Pin), I	10mA
Operating Temperature Range, T_A	-55 to +125°C
Storage Temperature Range, T_{stg}	-65 to +150°C

Note 1. These devices contain circuitry to protect the inputs against damage due to high static voltages or electric fields; however, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to this high impedance circuit. For proper operation it is recommended that V_{in} and V_{out} be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}).

Electrical Characteristics: (Voltages referenced to V_{SS}, Note 2)

Parameter	Symbol	V _{DD} Vdc	-55°C		+25°C			+125°C		Unit	
			Min	Max	Min	Typ	Max	Min	Max		
Output Voltage V _{in} = V _{DD} or 0	V _{OL}	5.0	—	0.05	—	0	0.05	—	0.05	Vdc	
		10	—	0.05	—	0	0.05	—	0.05	Vdc	
		15	—	0.05	—	0	0.05	—	0.05	Vdc	
	V _{OH}	5.0	4.95	—	4.95	5.0	—	4.95	—	Vdc	
		10	9.95	—	9.95	10	—	9.95	—	Vdc	
		15	14.95	—	14.95	15	—	14.95	—	Vdc	
Input Voltage (Note 4) (V _O = 4.5 or 0.5Vdc) (V _O = 9.0 or 1.0Vdc) (V _O = 13.5 or 1.5Vdc)	V _{IL}	5.0	—	1.5	—	2.25	1.5	—	1.5	Vdc	
		10	—	3.0	—	4.50	3.0	—	3.0	Vdc	
		15	—	4.0	—	6.75	4.0	—	4.0	Vdc	
	V _{IH}	5.0	3.5	—	3.5	2.75	—	3.5	—	Vdc	
		10	7.0	—	7.0	5.50	—	7.0	—	Vdc	
		15	11.0	—	11.0	8.25	—	11.0	—	Vdc	
Output Drive Current (V _{OH} = 2.5Vdc) (V _{OH} = 4.6Vdc) (V _{OH} = 9.5Vdc) (V _{OH} = 13.5Vdc)	Source	I _{OH}	5.0	-1.2	—	-1.0	-1.7	—	-0.7	—	mAdc
			5.0	-0.25	—	-0.2	-0.36	—	-0.14	—	mAdc
			10	-0.62	—	-0.5	-0.9	—	-0.35	—	mAdc
			15	-1.8	—	-1.5	-3.5	—	-1.1	—	mAdc
	Sink	I _{OL}	5.0	0.64	—	0.51	0.88	—	0.36	—	mAdc
			10	1.6	—	1.3	2.25	—	0.9	—	mAdc
			15	4.2	—	3.4	8.8	—	2.4	—	mAdc
Input Current	I _{in}	15	—	±0.1	—	±0.00001	±0.1	—	±0.1	μAdc	
Input Capacitance (V _{IN} = 0)	C _{in}	—	—	—	—	5.0	7.5	—	—	pF	
Quiescent Current (Per Package)	I _{DD}	5.0	—	5.0	—	0.005	5.0	—	150	μAdc	
		10	—	10	—	0.010	10	—	300	μAdc	
		15	—	15	—	0.015	15	—	600	μAdc	
Total Supply Current (Dynamic plus Quiescent, Per Package, C _L = 50pF on All Outputs, All Buffers Switching Note 3, Note 5)	I _T	5.0	I _T = (0.58μA/kHz) f + I _{DD}						—	μAdc	
		10	I _T = (1.2μA/kHz) f + I _{DD}						—	μAdc	
		15	I _T = (1.7μA/kHz) f + I _{DD}						—	μAdc	

Note 2. Data labeled "Typ" is not to be used for design purposes but is intended as an indication of the device's potential performance.

Note 3. The formulas given are for the typical characteristics only at +25°C.

Note 4. Noise immunity specified for worst-case input combination.

Noise margin for both "1" and "0" = 1.0Vdc min @ V_{DD} = 5Vdc

2.0Vdc min @ V_{DD} = 10Vdc

2.5Vdc min @ V_{DD} = 15Vdc

Note 5. To calculate total supply current at loads other than 50pF:

$$I_T(C_L) = I_T(50\text{pF}) + 1 \times 10^{-3}(C_L - 50) V_{DD}$$

where: I_T is in μA (per package), C_L in pF, V_{DD} in volts and f in kHz is input frequency.

Switching Characteristics: ($C_L = 50\text{pF}$, $T_A = +25^\circ\text{C}$, Note 2)

Parameter	Symbol	V_{DD}	Min	Typ	Max	Unit
		V_{dc}				
Output Rise Time $t_{TLH} = (3.0\text{ns/pf}) C_L + 30\text{ns}$ $t_{TLH} = (1.5\text{ns/pf}) C_L + 15\text{ns}$ $t_{TLH} = (1.1\text{ns/pf}) C_L + 10\text{ns}$	t_{TLH}	5.0	–	180	360	ns
		10	–	90	180	ns
		15	–	65	130	ns
Output Fall Time $t_{THL} = (1.5\text{ns/pf}) C_L + 25\text{ns}$ $t_{THL} = (0.75\text{ns/pf}) C_L + 12.5\text{ns}$ $t_{THL} = (0.55\text{ns/pf}) C_L + 9.5\text{ns}$	t_{THL}	5.0	–	100	200	ns
		10	–	50	100	ns
		15	–	40	80	ns
Propagation Delay Time Clock to Q $t_{PLH}, t_{PHL} = (1.7\text{ns/pf}) C_L + 230\text{ns}$ $t_{PLH}, t_{PHL} = (0.66\text{ns/pf}) C_L + 97\text{ns}$ $t_{PLH}, t_{PHL} = (0.5\text{ns/pf}) C_L + 75\text{ns}$ Clock to Carry Out $t_{PLH}, t_{PHL} = (1.7\text{ns/pf}) C_L + 230\text{ns}$ $t_{PLH}, t_{PHL} = (0.66\text{ns/pf}) C_L + 97\text{ns}$ $t_{PLH}, t_{PHL} = (0.5\text{ns/pf}) C_L + 75\text{ns}$ Carry In to Carry Out $t_{PLH}, t_{PHL} = (1.7\text{ns/pf}) C_L + 95\text{ns}$ $t_{PLH}, t_{PHL} = (0.66\text{ns/pf}) C_L + 47\text{ns}$ $t_{PLH}, t_{PHL} = (0.5\text{ns/pf}) C_L + 35\text{ns}$ Preset or Reset to Q $t_{PLH}, t_{PHL} = (1.7\text{ns/pf}) C_L + 230\text{ns}$ $t_{PLH}, t_{PHL} = (0.66\text{ns/pf}) C_L + 97\text{ns}$ $t_{PLH}, t_{PHL} = (0.5\text{ns/pf}) C_L + 75\text{ns}$ Preset or Reset to Carry Out $t_{PLH}, t_{PHL} = (1.7\text{ns/pf}) C_L + 465\text{ns}$ $t_{PLH}, t_{PHL} = (0.66\text{ns/pf}) C_L + 192\text{ns}$ $t_{PLH}, t_{PHL} = (0.6\text{ns/pf}) C_L + 125\text{ns}$	t_{PLH}, t_{PHL}	5.0	–	315	630	ns
		10	–	130	260	ns
		15	–	100	200	ns
		5.0	–	315	630	ns
		10	–	130	260	ns
		15	–	100	200	ns
		5.0	–	180	360	ns
		10	–	80	160	ns
		15	–	60	120	ns
		5.0	–	315	630	ns
		10	–	130	260	ns
		15	–	100	200	ns
Clock Pulse Width	t_{WH}	5.0	350	200	–	ns
		10	170	100	–	ns
		15	140	75	–	ns
Clock Pulse Frequency	f_{cl}	5.0	–	3.0	1.5	MHz
		10	–	6.0	3.0	MHz
		15	–	8.0	4.0	MHz
Preset or Reset Removal Time (Note 6)	t_{rem}	5.0	650	325	–	ns
		10	230	115	–	ns
		15	180	90	–	ns
Clock Rise and Fall Time	t_{TLH}, t_{THL}	5.0	–	–	15	μs
		10	–	–	15	μs
		15	–	–	15	μs

Note 2. Data labeled "Typ" is not to be used for design purposes but is intended as an indication of the device's potential performance.

Note 3. The formulas given are for the typical characteristics only at $+25^\circ\text{C}$.

Note 6. The Preset or Reset Signal must be low prior to a positive-going transition of the clock.

Switching Characteristics (Cont'd): ($C_L = 50\text{pF}$, $T_A = +25^\circ\text{C}$, Note 2)

Parameter	Symbol	V_{DD} V_{dc}	Min	Typ	Max	Unit
Carry In Setup Time	t_{SU}	5.0	200	130	—	ns
		10	120	60	—	ns
		15	100	50	—	ns
Up/Down Setup Time	t_{SU}	5.0	500	250	—	ns
		10	200	100	—	ns
		15	175	75	—	ns
Preset Enable Pulse Width	t_{WH}	5.0	200	100	—	ns
		10	100	50	—	ns
		15	80	40	—	ns

Note 2. Data labeled "Typ" is not to be used for design purposes but is intended as an indication of the device's potential performance.

Note 3. The formulas given are for the typical characteristics only at $+25^\circ\text{C}$.

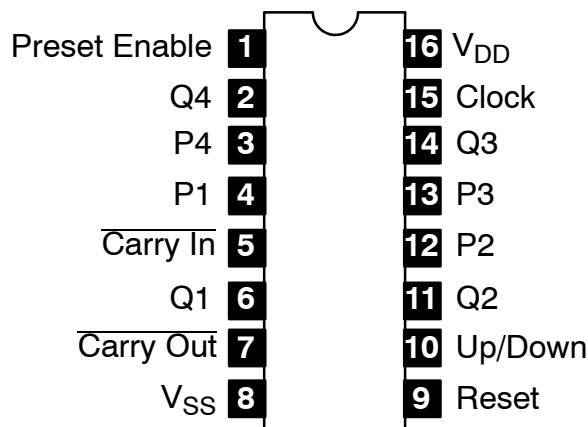
Note 6. The Preset or Reset Signal must be low prior to a positive-going transition of the clock.

Truth Table:

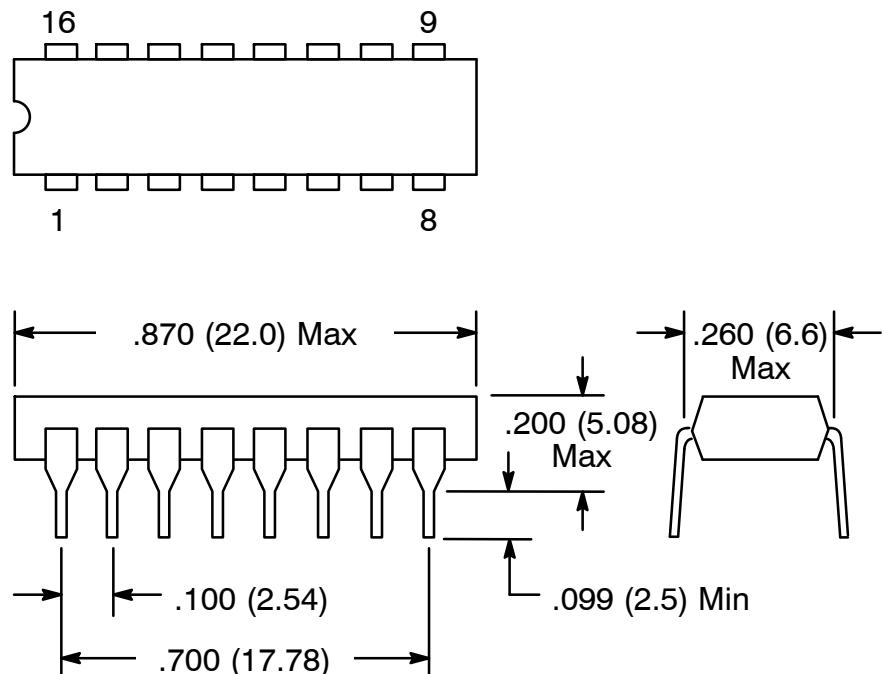
Carry In	Up/Down	Preset Enable	Reset	Action
1	X	0	0	No Count
0	1	0	0	Count Up
0	0	0	0	Count Down
X	X	1	0	Preset
X	X	X	1	Reset

X = Don't Care

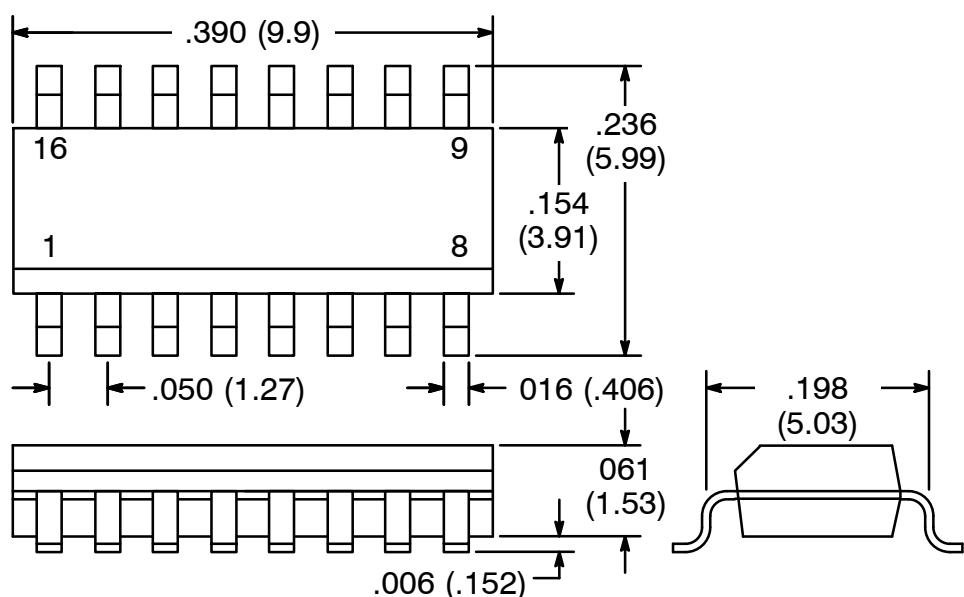
Pin Connection Diagram



NTE4510B



NTE4510BT



NOTE: Pin1 on Beveled Edge